



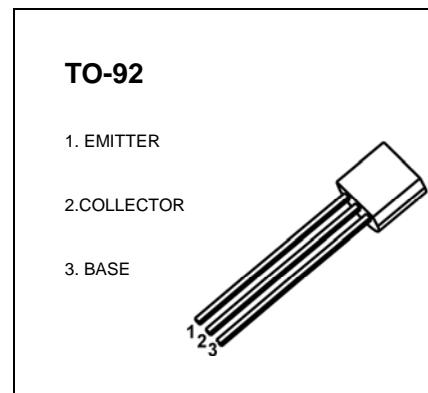
JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD

TO-92 Plastic-Encapsulate Transistors

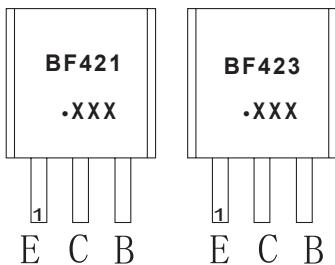
BF421 TRANSISTOR (PNP)
BF423

FEATURES

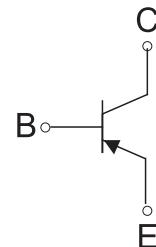
- Low Feedback Capacitance.
- PNP Transistors in a TO-92 Plastic Package.
- NPN Complements: BF420 and BF422
- Class-B Video Output Stages in Colour Television and Professional Monitor Equipment.



MARKING



Equivalent Circuit



BF421,BF423=Device code

Solid dot=Green molding compound device,
if none,the normal device
XXX=Code

ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
BF421	TO-92	Bulk	1000pcs/Bag
BF421-TA	TO-92	Tape	2000pcs/Box
BF423	TO-92	Bulk	1000pcs/Bag
BF423-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

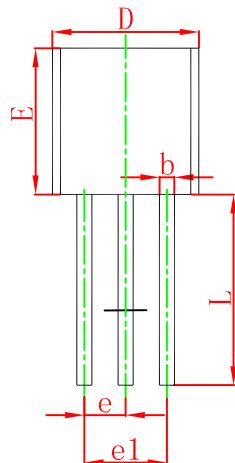
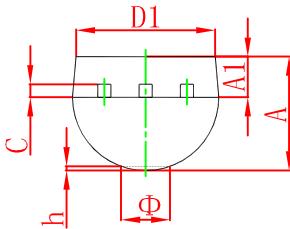
Symbol	Parameter	BF421	BF423	Unit
V_{CBO}	Collector-Base Voltage	-300	-250	V
V_{CEO}	Collector-Emitter Voltage	-300	-250	V
V_{EBO}	Emitter-Base Voltage	-5		V
I_c	Collector Current -Continuous	-100		mA
P_c	Collector Power Dissipation	0.83		W
R_{thja}	Thermal resistance from junction to ambient	151		$^\circ\text{C}/\text{W}$
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55 ~ +150		$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

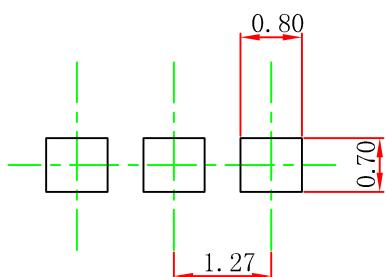
$T_a=25^\circ C$ unless otherwise specified

Parameter		Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	BF421 BF423	$V_{(BR)CBO}$	$I_C=-100\mu A, I_E=0$	-300 -250		V
Collector-emitter breakdown voltage	BF421 BF423	$V_{(BR)CEO}$	$I_C= -1mA, I_B=0$	-300 -250		V
Emitter-base breakdown voltage		$V_{(BR)EBO}$	$I_E=-100\mu A, I_C=0$	-5		V
Collector cut-off current		I_{CBO}	$V_{CB}=-200 V, I_E=0$		-0.01	μA
Emitter cut-off current	BF421 BF423	I_{EBO}	$V_{EB}=-5V, I_C=0$		-0.1 -0.05	μA
DC current gain		h_{FE}	$V_{CE}=-20V, I_C=-25mA$	50		
Collector-emitter saturation voltage	BF421 BF423	$V_{CE(sat)}$	$I_C=-20mA, I_B=-2mA$ $I_C=-30mA, I_B=-5mA$		-0.6	V
Transition frequency		f_T	$V_{CE}=-10V, I_C=-10mA$ $f = 100MHz$	60		MHz
Feedback capacitance		C_{re}	$V_{CE}=-30V, I_C=0, f=1MHz$		1.6	pF

TO-92 Package Outline Dimensions



TO-92 Suggested Pad Layout



Note:

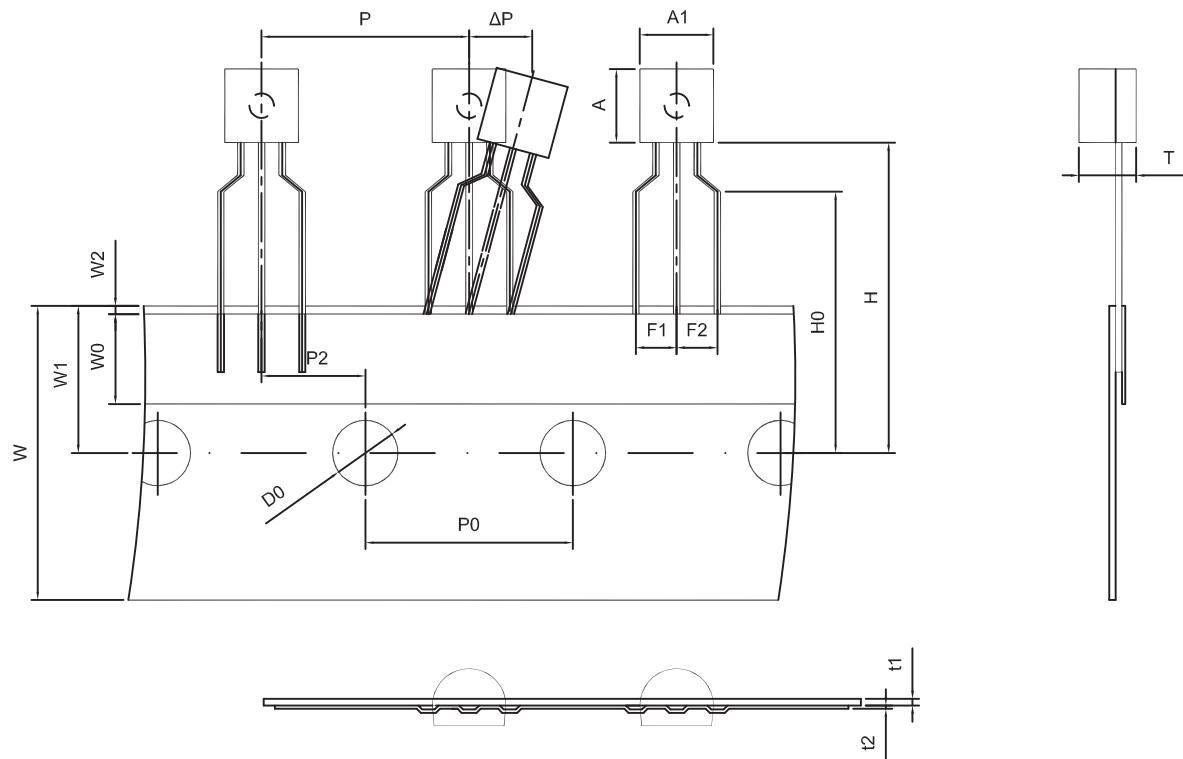
1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

NOTICE

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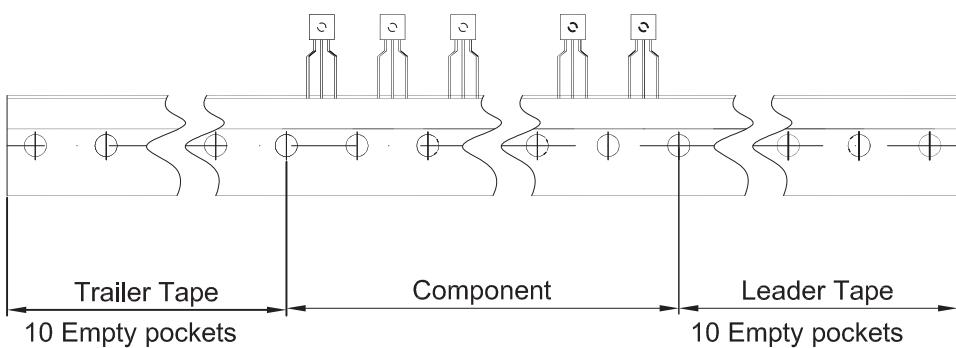
TO-92 Tape and Reel

TO-92 PACKAGE TAPING DIMENSION



Dimensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250

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